



Vishay General Semiconductor

# Ultra Low V<sub>F</sub> Surface Mount Schottky Barrier Rectifiers

# eSMP<sup>™</sup> Series Top View **Bottom View MicroSMP**

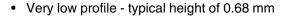
The ultra low V<sub>F</sub> Schottky optimized for forward voltage drop with high reverse current trade-off.

PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	1 A			
V <sub>RRM</sub>	20 V, 30 V			
I <sub>FSM</sub>	30 A			
V <sub>F</sub> at I <sub>F</sub> = 1.0 A	0.30 V			
T <sub>J</sub> max.	125 °C			

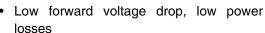
#### **APPLICATIONS**

Application designed and qualified for hard disk driver where the V<sub>F</sub> performance and size are required. HTIR is not a concern.

#### **FEATURES**









· Caution: High reverse leakage

- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21 definition

#### **MECHANICAL DATA**

Case: MicroSMP

Molding compound meets UL 94 V-0 flammability

Base P/N-M3 - halogen-free and RoHS compliant, commercial grade

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test Polarity: Color band denotes the cathode end

MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	MSS1P2U	MSS1P3U	UNIT	
Device marking code		12U	13U		
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	20 30		٧	
Maximum average forward rectified current at $T_{\rm M}$ = 110 °C	I <sub>F</sub>	1.0		Α	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I <sub>FSM</sub>	30		А	
Operating junction temperature range	T <sub>J</sub>	- 55 to + 125		°C	
Storage temperature range	T <sub>STG</sub>	- 55 to + 150		°C	

### MSS1P2U & MSS1P3U

### Vishay General Semiconductor



<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage (1)	$I_F = 0.1 A$ $I_F = 0.5 A$ $I_F = 1.0 A$	T <sub>A</sub> = 25 °C	V <sub>F</sub>	0.23 0.30 0.35	- - 0.40	V
	$I_F = 0.1 \text{ A}$ $I_F = 0.5 \text{ A}$ $I_F = 1.0 \text{ A}$	T <sub>A</sub> = 85 °C		0.16 0.24 0.30	- - 0.35	
Reverse current per diode (2)	V <sub>R</sub> = 30 V	T <sub>A</sub> = 25 °C T <sub>A</sub> = 85 °C	I <sub>R</sub>	0.4 12	1.2 30	mA
Typical junction capacitance	4.0 V, 1 MHz		CJ	68	-	pF

#### Notes:

- (1) Pulse test: 300  $\mu$ s pulse width, 1 % duty cycle
- (2) Pulse test: Pulse width  $\leq$  40 ms
- Reverse power dissipation and the possibility of thermal runaway must be considered when operating this device under any reverse voltage
  conditions. Calculations of T<sub>J</sub> therefore must include forward and reverse power effects.

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	MSS1P2U	MSS1P3U	UNIT	
Typical thermal resistance (1)	$R_{ hetaJA} \ R_{ hetaJM}$	170 30		°C/W	

#### Note:

(1) Free air, mounted on recommended copper pad area. Thermal resistance R<sub>θJA</sub> - junction to ambient, R<sub>θJM</sub> - junction to mount.

ORDERING INFORMATION (Example)						
PREFERRED P/N UNIT WEIGHT (g) PREFERRED PACKAGE CODE BAS				DELIVERY MODE		
MSS1P3U-M3/89A	0.006	89A	4500	7" diameter plastic tape and reel		

### **RATINGS AND CHARACTERISTICS CURVES**

(T<sub>A</sub> = 25 °C unless otherwise noted)

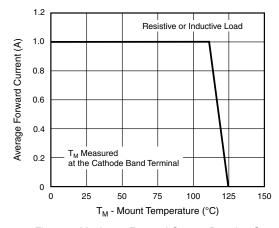


Figure 1. Maximum Forward Current Derating Curve

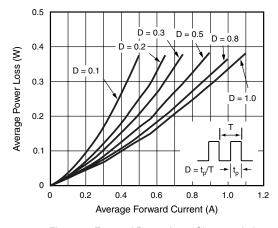


Figure 2. Forward Power Loss Characteristics

### MSS1P2U & MSS1P3U



## Vishay General Semiconductor

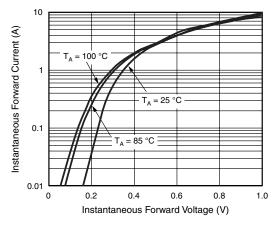


Figure 3. Typical Instantaneous Forward Characteristics

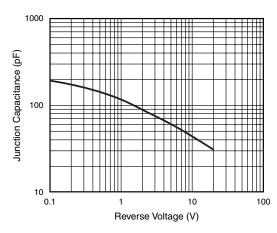


Figure 5. Typical Junction Capacitance

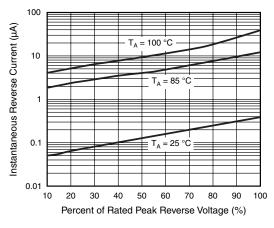


Figure 4. Typical Reverse Characteristics

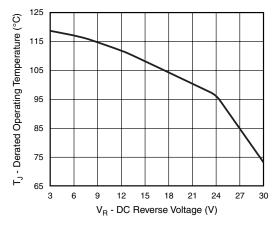
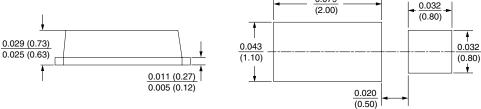


Figure 6. Typical Operating Temperature Derating

### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)

#### **MicroSMP** 0.059 (1.50) 0.030 (0.75) Cathode Band 0.043 (1.10) 0.022 (0.55) 0.055 (1.40) 0.047 (1.20) 0.030 (0.75) 0.039 (0.98) 0.031 (0.78) 0.022 (0.55) 0.091 (2.30) 0.083 (2.10) 0.106 (2.70) 0.091 (2.30) **Mounting Pad Layout** 0.079 0.032 (2.00)



Document Number: 89095 Revision: 17-Mar-09

0.032



Vishay

### **Disclaimer**

All product specifications and data are subject to change without notice.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained herein or in any other disclosure relating to any product.

Vishay disclaims any and all liability arising out of the use or application of any product described herein or of any information provided herein to the maximum extent permitted by law. The product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein, which apply to these products.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications unless otherwise expressly indicated. Customers using or selling Vishay products not expressly indicated for use in such applications do so entirely at their own risk and agree to fully indemnify Vishay for any damages arising or resulting from such use or sale. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

Product names and markings noted herein may be trademarks of their respective owners.

Revision: 18-Jul-08

Document Number: 91000 www.vishay.com